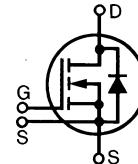


HiPerFET™ Power MOSFETs

N-Channel Enhancement Mode
Avalanche Rated, High dv/dt, Low t_{rr}

IXFN 200 N06
IXFN 180 N07
IXFN 200 N07

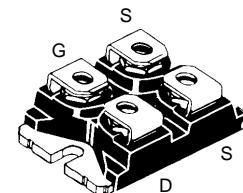


| V_{DSS} | I_{D25} | $R_{DS(on)}$ |
|-----------|-----------|--------------|
| 60 V | 200 A | 6 mΩ |
| 70 V | 180 A | 7 mΩ |
| 70 V | 200 A | 6 mΩ |

$t_{rr} \leq 250$ ns

miniBLOC, SOT-227 B (IXFN)

E153432



G = Gate D = Drain

S = Source

Either Source terminal at miniBLOC can be used as Main or Kelvin Source

| Symbol | Test Conditions | Maximum Ratings | | |
|---------------|---|--------------------|------------------|----|
| V_{DSS} | $T_J = 25^\circ\text{C}$ to 150°C | N07 | 70 | V |
| | | N06 | 60 | V |
| V_{DGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GS} = 1\text{ M}\Omega$ | N07 | 70 | V |
| | | N06 | 60 | V |
| V_{GS} | Continuous | | ± 20 | V |
| V_{GSM} | Transient | | ± 30 | V |
| I_{D25} | $T_c = 25^\circ\text{C}$; Chip capability | 200N06/200N07 | 200 | A |
| | | 180N07 | 180 | A |
| $I_{L(RMS)}$ | Terminal current limit | | 100 | A |
| I_{DM} | $T_c = 25^\circ\text{C}$, pulse width limited by T_{JM} | 600 | A | |
| I_{AR} | $T_c = 25^\circ\text{C}$ | 100 | A | |
| E_{AR} | $T_c = 25^\circ\text{C}$ | 30 | mJ | |
| E_{AS} | $T_c = 25^\circ\text{C}$ | 2 | J | |
| dv/dt | $I_S \leq I_{DM}$, $dI/dt \leq 100\text{ A}/\mu\text{s}$, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ\text{C}$, $R_G = 2\Omega$ | 5 | V/ns | |
| P_D | $T_c = 25^\circ\text{C}$ | 520 | W | |
| T_J | | -55 ... +150 | $^\circ\text{C}$ | |
| T_{JM} | | 150 | $^\circ\text{C}$ | |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ | |
| V_{ISOL} | 50/60 Hz, RMS $I_{ISOL} \leq 1\text{ mA}$ | $t = 1\text{ min}$ | 2500 | V~ |
| | | $t = 1\text{ s}$ | 3000 | V~ |
| M_d | Mounting torque Terminal connection torque | | 1.5/13Nm/lb.in. | |
| | | | 1.5/13Nm/lb.in. | |
| Weight | | 30 | g | |

| Symbol | Test Conditions | Characteristic Values | | |
|--------------|---|--|-----------|------------------|
| | | ($T_J = 25^\circ\text{C}$, unless otherwise specified) | min. | typ. |
| V_{DSS} | $V_{GS} = 0\text{ V}$, $I_D = 1\text{ mA}$ | N06 | 60 | V |
| | | N07 | 70 | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 8\text{ mA}$ | 2 | 4 | V |
| I_{GSS} | $V_{GS} = \pm 20\text{ V}_DC$, $V_{DS} = 0$ | | ± 200 | nA |
| I_{DSS} | $V_{DS} = 0.8 \cdot V_{DSS}$ $V_{GS} = 0\text{ V}$ $T_J = 125^\circ\text{C}$ | $T_J = 25^\circ\text{C}$ | 400 | μA |
| | | | 2 | mA |
| $R_{DS(on)}$ | $V_{GS} = 10\text{ V}$, $I_D = 0.5 \cdot I_{D25}$ Pulse test, $t \leq 300\text{ }\mu\text{s}$, duty cycle d $\leq 2\%$ | 200N06/200N07 180N07 | 6 | $\text{m}\Omega$ |
| | | | 7 | $\text{m}\Omega$ |

IXYS reserves the right to change limits, test conditions, and dimensions.

97533A (9/99)

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| Symbol | Test Conditions | Characteristic Values | | | |
|---|--|--|------|------|------|
| | | ($T_j = 25^\circ\text{C}$, unless otherwise specified) | min. | typ. | max. |
| g_{fs} | $V_{DS} = 10 \text{ V}; I_D = 0.5 \cdot I_{D25}$, pulse test | 60 | 80 | S | |
| C_{iss} C_{oss} C_{rss} | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$ | 9000 | | pF | |
| | | 4000 | | pF | |
| | | 2400 | | pF | |
| $t_{d(on)}$ t_r $t_{d(off)}$ t_f | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ $R_G = 1 \Omega$ (External), | 30 | | ns | |
| | | 60 | | ns | |
| | | 100 | | ns | |
| | | 60 | | ns | |
| $Q_{g(on)}$ Q_{gs} Q_{gd} | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ | 480 | | nC | |
| | | 60 | | nC | |
| | | 240 | | nC | |
| R_{thJC} | miniBLOC, SOT-227 B | | 0.24 | K/W | |
| R_{thCK} | miniBLOC, SOT-227 B | | 0.05 | K/W | |

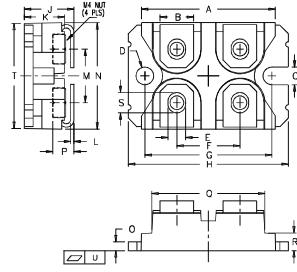
Source-Drain Diode

Characteristic Values

 $(T_j = 25^\circ\text{C}, \text{unless otherwise specified})$

| Symbol | Test Conditions | min. | typ. | max. |
|----------------------------------|---|-------------------------|------|---------------|
| I_s | $V_{GS} = 0 \text{ V}$ | 200N06/200N07 180N07 | | A |
| | | | 200 | A |
| | | | 180 | A |
| I_{SM} | Repetitive; pulse width limited by T_{JM} | | 600 | A |
| V_{SD} | $I_F = 100 \text{ A}, V_{GS} = 0 \text{ V},$ Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2 \%$ | | 1.7 | V |
| t_{rr} Q_{RM} I_{RM} | $I_F = 25 \text{ A}$ $-di/dt = 100 \text{ A}/\mu\text{s},$ $V_R = 50 \text{ V}$ | 150 | 250 | ns |
| | | 0.7 | | μC |
| | | 9 | | A |

miniBLOC, SOT-227 B



M4 screws (4x) supplied

| Dim. | Millimeter Min. | Millimeter Max. | Inches Min. | Inches Max. |
|------|--------------------|--------------------|----------------|----------------|
| A | 31.50 | 31.88 | 1.240 | 1.255 |
| B | 7.80 | 8.20 | 0.307 | 0.323 |
| C | 4.09 | 4.29 | 0.161 | 0.169 |
| D | 4.09 | 4.29 | 0.161 | 0.169 |
| E | 4.09 | 4.29 | 0.161 | 0.169 |
| F | 14.91 | 15.11 | 0.587 | 0.595 |
| G | 30.12 | 30.30 | 1.186 | 1.193 |
| H | 38.00 | 38.23 | 1.496 | 1.505 |
| J | 11.68 | 12.22 | 0.460 | 0.481 |
| K | 8.92 | 9.60 | 0.351 | 0.378 |
| L | 0.76 | 0.84 | 0.030 | 0.033 |
| M | 12.60 | 12.85 | 0.496 | 0.506 |
| N | 25.15 | 25.42 | 0.990 | 1.001 |
| O | 1.98 | 2.13 | 0.078 | 0.084 |
| P | 4.95 | 5.97 | 0.195 | 0.235 |
| Q | 26.54 | 26.90 | 1.045 | 1.059 |
| R | 3.94 | 4.42 | 0.155 | 0.174 |
| S | 4.72 | 4.85 | 0.186 | 0.191 |
| T | 24.59 | 25.07 | 0.968 | 0.987 |
| U | -0.05 | 0.1 | -0.002 | 0.004 |

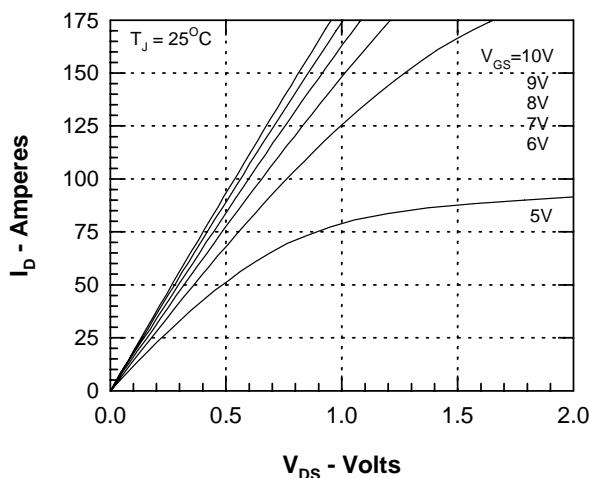


Figure 1. Output Characteristics at 25°C

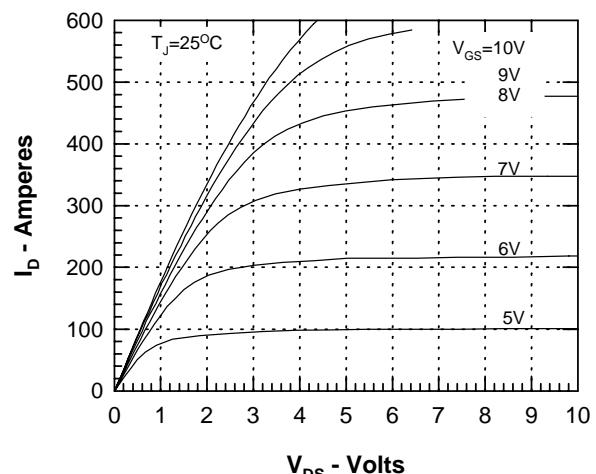


Figure 2. Extended Output Characteristics

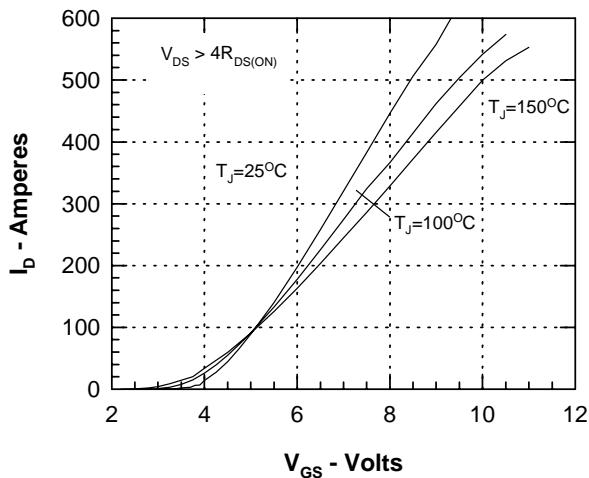


Figure 3. Admittance Curves

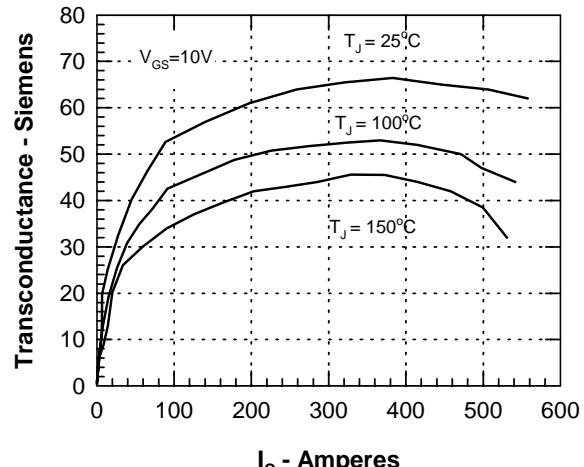


Figure 4. Transconductance vs.
Drain Current

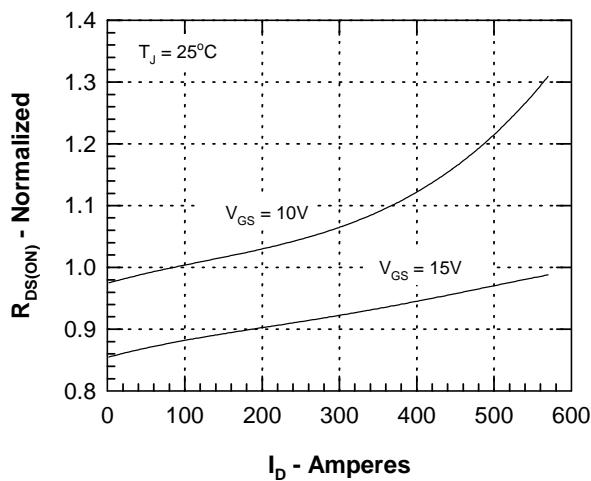


Figure 5. $R_{DS(\text{ON})}$ normalized to $0.5 I_{D25}$ value

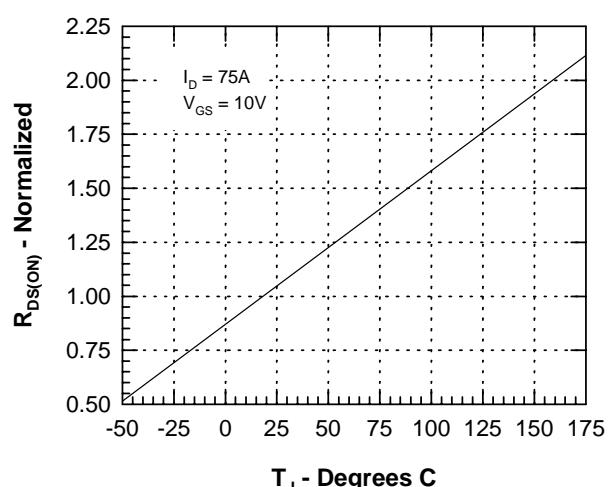


Figure 6. Normalized $R_{DS(\text{ON})}$ vs. Junction
Temperature

